Quad 2-Input OR Gate

High-Performance Silicon-Gate CMOS

Features

- Outputs Source/Sink 24 mA
- 'ACT32 Has TTL Compatible Inputs
- These Devices are Pb-Free and are RoHS Compliant

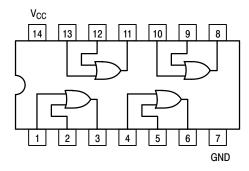


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)



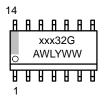
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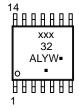
SOIC-14 D SUFFIX CASE 751A





1

TSSOP-14 DT SUFFIX CASE 948G



xxx = AC or ACT

A = Assembly Location

WL or L = Wafer Lot Y = Year WW or W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Parameter | | Value | Unit |
|-----------------------|--|---|-----------------------------------|------|
| V _{CC} | DC Supply Voltage | | -0.5 to +7.0 | V |
| VI | DC Input Voltage | | $-0.5 \le V_{I} \le V_{CC} + 0.5$ | V |
| Vo | DC Output Voltage | (Note 1) | $-0.5 \le V_O \le V_{CC} + 0.5$ | V |
| I _{IK} | DC Input Diode Current | | ±20 | mA |
| I _{OK} | DC Output Diode Current | | ±50 | mA |
| Io | DC Output Sink/Source Current | | ±50 | mA |
| Icc | DC Supply Current per Output Pin | | ±50 | mA |
| I _{GND} | DC Ground Current per Output Pin | | ±50 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| TL | Lead temperature, 1 mm from Case for 10 Seconds | 3 | 260 | °C |
| TJ | Junction temperature under Bias | | +150 | °C |
| $\theta_{\sf JA}$ | Thermal Resistance (Note 2) | SOIC TSSOP | 125 170 | °C/W |
| P _D | Power Dissipation in Still Air at 85°C | SOIC TSSOP | 125 170 | mW |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating Oxyge | en Index: 30% – 35% | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | Ma | Body Model (Note 3) achine Model (Note 4) Device Model (Note 5) | > 2000 > 200 > 1000 | V |
| I _{Latch-Up} | Latch-Up Performance Above V _{CC} and Below 0 | GND at 85°C (Note 6) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. I_O absolute maximum rating must be observed.
- 2. The package thermal impedance is calculated in accordance with JESD51-7.
- 3. Tested to EIA/JESD22-A114-A.
- 4. Tested to EIA/JESD22-A115-A.
- Tested to JESD22-C101-A.
- 6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Тур | Max | Unit |
|------------------------------------|---|-------------------------|-----|-----|-----------------|------|
| ., | 0.177 | 'AC | 2.0 | 5.0 | 6.0 | ., |
| V_{CC} | V _{CC} Supply Voltage | 'ACT | 4.5 | 5.0 | 5.5 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Ref. to GND) | | 0 | _ | V _{CC} | V |
| | | | - | 150 | _ | |
| t _r , t _f | t _r , t _f Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs | V _{CC} @ 4.5 V | - | 40 | _ | ns/V |
| | | V _{CC} @ 5.5 V | - | 25 | _ | |
| | Input Rise and Fall Time (Note 2) | V _{CC} @ 4.5 V | - | 10 | _ | 0.4 |
| t _r , t _f | 'ACT Devices except Schmitt Inputs | V _{CC} @ 5.5 V | - | 8.0 | _ | ns/V |
| TJ | Junction Temperature (PDIP) | | - | _ | 140 | °C |
| T _A | Operating Ambient Temperature Range | | -40 | 25 | 85 | °C |
| Гон | Output Current – High | | - | _ | -24 | mA |
| l _{OL} | Output Current – Low | | _ | _ | 24 | mA |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- V_{in} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.
 V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

| | | | 74 | AC | 74AC | | |
|------------------|--------------------------------------|---------------------|-------------------------|----------------------|---------------------------------------|------|--|
| Symbol | Parameter | V _{CC} (V) | T _A = +25°C | | T _A = -40°C to +85°C | Unit | Conditions |
| | | | Тур | Guar | anteed Limits | | |
| V _{IH} | Minimum High Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 2.1 3.15 3.85 | 2.1 3.15 3.85 | V | V _{OUT} = 0.1 V or V _{CC} - 0.1 V |
| V _{IL} | Maximum Low Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 0.9 1.35 1.65 | 0.9 1.35 1.65 | V | V _{OUT} = 0.1 V or V _{CC} - 0.1 V |
| V _{OH} | Minimum High Level Output Voltage | 3.0 4.5 5.5 | 2.99 4.49 5.49 | 2.9 4.4 5.4 | 2.9 4.4 5.4 | V | I _{OUT} = -50 μA |
| | | 3.0 4.5 5.5 | - - - | 2.56 3.86 4.86 | 2.46 3.76 4.76 | V | * V _{IN} = V _{IL} or V _{IH} -12 mA I_{OH} -24 mA -24 mA |
| V _{OL} | Maximum Low Level Output Voltage | 3.0 4.5 5.5 | 0.002 0.001 0.001 | 0.1 0.1 0.1 | 0.1 0.1 0.1 | V | Ι _{ΟUT} = 50 μΑ |
| | | 3.0 4.5 5.5 | - - - | 0.36 0.36 0.36 | 0.44 0.44 0.44 | V | * V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA |
| I _{IN} | Maximum Input Leakage Current | 5.5 | - | ±0.1 | ±1.0 | μΑ | $V_I = V_{CC}$, GND |
| I _{OLD} | †Minimum Dynamic | 5.5 | - | - | 75 | mA | V _{OLD} = 1.65 V Max |
| I _{OHD} | Output Current | 5.5 | _ | - | - 75 | mA | V _{OHD} = 3.85 V Min |
| I _{CC} | Maximum Quiescent Supply Current | 5.5 | - | 4.0 | 40 | μΑ | V _{IN} = V _{CC} or GND |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. *All outputs loaded; thresholds on input associated with output under test.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

AC CHARACTERISTICS

| | | | | 74AC | | 74 | AC | | |
|------------------|-------------------|------------|--|------------|---|------------|-------------|-------------|-----|
| Symbol | Symbol Parameter | | T _A = +25°C C _L = 50 pF | | $T_A = -40^{\circ}C$ to +85°C $C_L = 50 \text{ pF}$ | | Unit | Fig. No. | |
| | | | Min | Тур | Max | Min | Max | | |
| t _{PLH} | Propagation Delay | 3.3 5.0 | 1.5 1.5 | 7.0 5.5 | 9.0 7.5 | 1.5 1.0 | 10.0 8.5 | ns | 3–5 |
| t _{PHL} | Propagation Delay | 3.3 5.0 | 1.5 1.5 | 7.0 5.0 | 8.5 7.0 | 1.0 1.0 | 9.0 7.5 | ns | 3–5 |

^{*}Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

[†]Maximum test duration 2.0 ms, one output loaded at a time.

DC CHARACTERISTICS

| | | | 74 <i>P</i> | CT | 74ACT | | |
|------------------|--|---------------------|------------------------|--------------|---------------------------------------|------|---|
| Symbol | Parameter | V _{CC} (V) | T _A = +25°C | | T _A = -40°C to +85°C | Unit | Conditions |
| | | | Тур | Guar | anteed Limits | | |
| V _{IH} | Minimum High Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 2.0 2.0 | 2.0 2.0 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{IL} | Maximum Low Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 0.8 0.8 | 0.8 0.8 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{OH} | Minimum High Level Output Voltage | 4.5 5.5 | 4.49 5.49 | 4.4 5.4 | 4.4 5.4 | V | I _{OUT} = -50 μA |
| | | 4.5 5.5 | _ _ | 3.86 4.86 | 3.76 4.76 | V | $^*V_{IN} = V_{IL} \text{ or } V_{IH}$ -24 mA I_{OH} -24 mA |
| V _{OL} | Maximum Low Level Output Voltage | 4.5 5.5 | 0.001 0.001 | 0.1 0.1 | 0.1 0.1 | V | I _{OUT} = 50 μA |
| | | 4.5 5.5 | _ _ | 0.36 0.36 | 0.44 0.44 | V | $^*V_{IN} = V_{IL} \text{ or } V_{IH}$ $^{24} \text{ mA}$ ^{1}OL $^{24} \text{ mA}$ |
| I _{IN} | Maximum Input Leakage Current | 5.5 | _ | ±0.1 | ±1.0 | μА | $V_I = V_{CC}$, GND |
| ΔI_{CCT} | Additional Max. I _{CC} /Input | 5.5 | 0.6 | - | 1.5 | mA | V _I = V _{CC} – 2.1 V |
| I _{OLD} | †Minimum Dynamic | 5.5 | _ | - | 75 | mA | V _{OLD} = 1.65 V Max |
| I _{OHD} | Output Current | 5.5 | - | - | -75 | mA | V _{OHD} = 3.85 V Min |
| Icc | Maximum Quiescent Supply Current | 5.5 | - | 4.0 | 40 | μΑ | $V_{IN} = V_{CC}$ or GND |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS

| | Parameter | | | 74ACT | | 74A | СТ | | |
|------------------|-------------------|--------------------------|--|-------|--|-----|------|-------------|-----|
| Symbol | | V _{CC} * (V) | T _A = +25°C C _L = 50 pF | | T _A = -40°C to +85°C C _L = 50 pF | | Unit | Fig. No. | |
| | | | Min | Тур | Max | Min | Max | | |
| t _{PLH} | Propagation Delay | 5.0 | 1.0 | _ | 9.0 | 1.0 | 10.0 | ns | 3–6 |
| t _{PHL} | Propagation Delay | 5.0 | 1.0 | ı | 9.0 | 1.0 | 10.0 | ns | 3–6 |

^{*}Voltage Range 5.0 V is 5.0 V \pm 0.5 V.

CAPACITANCE

| Symbol | Parameter | Value Typ | Unit | Test Conditions |
|-----------------|-------------------------------|--------------|------|-------------------------|
| C _{IN} | Input Capacitance | 4.5 | pF | V _{CC} = 5.0 V |
| C _{PD} | Power Dissipation Capacitance | 20 | pF | V _{CC} = 5.0 V |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|-----------------------|-----------------------|
| MC74AC32DG | SOIC-14 | 55 Units / Rail |
| MC74AC32DR2G | (Pb-Free) | 2500 Units / Reel |
| MC74AC32DTR2G | TSSOP-14 (Pb-Free) | 2500 Units / Reel |
| MC74ACT32DG | SOIC-14 | 55 Units / Rail |
| MC74ACT32DR2G | (Pb-Free) | 2500 Units / Reel |
| MC74ACT32DTR2G | TSSOP-14 (Pb-Free) | 2500 Units / Reel |

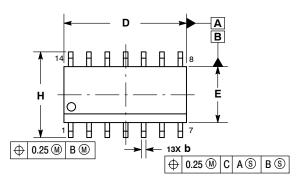
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



△ 0.10

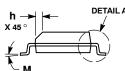
SOIC-14 NB CASE 751A-03 ISSUE L

DATE 03 FEB 2016









- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 - DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

| | MILLIN | IETERS | INC | HES |
|-----|---------|--------|-------|-------|
| DIM | MIN MAX | | MIN | MAX |
| Α | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| АЗ | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| Е | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 | BSC | 0.050 | BSC |
| Н | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| М | 0 ° | 7° | 0 ° | 7 ° |

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator. "G" or microdot " ■". may or may not be present.

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DIMENSIONS: MILLIMETERS

C SEATING PLANE

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOIC-14 CASE 751A-03 ISSUE L

DATE 03 FEB 2016

| STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 2: CANCELLED | STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE | STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE |
|---|---|---|---|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

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DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY.
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 4.90 | 5.10 | 0.193 | 0.200 |
| В | 4.30 | 4.50 | 0.169 | 0.177 |
| С | | 1.20 | | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| Н | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| М | 0° | 8 ° | 0 ° | 8 ° |

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot ٧ = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| ◀ | 7.06 |
|---------------|--|
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| | 0.65 |
| , <u> </u> | — — — • • • • • • • • • • • • • • • • • • • |
| 14X | ─ |
| 0.36 14X 1.26 | DIMENSIONS: MILLIMETERS |

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NLX1G11AMUTCG NLX1G97MUTCG 74LS38 74LVC32ADTR2G MC74HCT20ADTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G
NLV74HC02ADR2G 74HC32S14-13 74LS133 74LVC1G32Z-7 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7
NLV74HC08ADTR2G NLV74HC14ADR2G NLV74HC20ADR2G NLX2G86MUTCG 5962-8973601DA 74LVC2G02HD4-7
NLU1G00AMUTCG 74LVC2G32RA3-7 74LVC2G00HD4-7 NL17SG02P5T5G 74LVC2G00HK3-7 74LVC2G86HK3-7
NLX1G99DMUTWG NLVVHC1G00DFT2G NLVHC1G08DFT2G NLV7SZ57DFT2G NLV74VHC04DTR2G NLV27WZ86USG
NLV27WZ00USG NLU1G86CMUTCG NLU1G08CMUTCG NL17SZ32P5T5G NL17SZ00P5T5G NL17SH02P5T5G 74AUP2G00RA3-7
NLV74HC02ADTR2G NLX1G332CMUTCG NL17SG86P5T5G NL17SZ05P5T5G